Low loss and excellent stability of Zn_{0.7}Mg_{0.3}TiO₃ ceramics added V₂O₅-TiO₂ for implementing low-temperature co-fired ceramic technology

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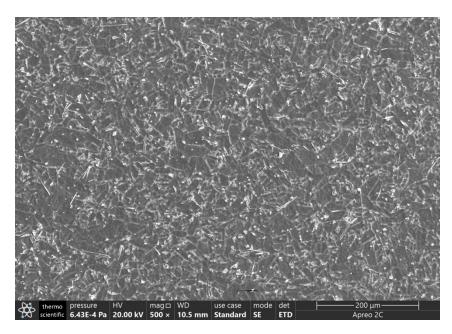
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Results



SFig. 1 SEM image of the $Zn_{0.7}Mg_{0.3}TiO_3$ ceramics.

The dielectric properties of the $Zn_{0.7}Mg_{0.3}TiO_3$ ceramic sintered at 1150°C for 4h.

Sample	$oldsymbol{arepsilon}_r$	$Q \times f$	$ au_f$
$Zn_{0.7}Mg_{0.3}TiO_3$	21.714	48486.6	-16.31204951